

PIN Diode Switches Technical Data Sheet

Features

- Reflective SPDT High Power PIN Diode Switch
- · GaN Semiconductor Technology
- Reflective Design
- Frequency Range: 500 MHz to 18 GHz
- Insertion Loss: 1.7 dB typ
- Isolation: 40 dB typ
- VSWR: 1.35:1 typ
- Maximum RF Input Power: +46 dBm

Applications

- Aerospace & Defense
- Microwvae Radio
- Military & Commercial
- Communication
- VSAT
- SATCOM

- Input IP3: +50 dBm typ
- Switching Speed: < 100 nsec
- TTL Compatible Driver Circuitry
- 50 Ohm Design
- SMA Female Connectors
- Compact Package Design withstands up to 95% Relative Humidity
- -45°C to +85°C Operating Temperature
 - Test & Measuurement
 - Wireless Infrastructure
 - Fiber Optics

Description

The PE71S1109 is a high power Reflective SP4T PIN Diode Switch that operates from DC to 6 GHz and incorporates and integrated heatsink to ensure optimum thermal dissipation for highly reliable operation. The module utilizes Gallium Nitride (GaN) and chip-and-wire technology in the manufacturing process that ensures state-of-the-art power performance with excellent power-to-volume ratio that's ideal for broadband high power applications. The 50 ohm reflective design has impressive RF input power handling capability for cold switching up to +46 dBm, and incorporates TTL compatible driver circuitry for accurate logic control. Typical performance includes 1.7 dB insertion loss, 40 dB isolation, 1.35:1 VSWR, and < 100 nsec switching speed. Operational temperature range is -45°C to +85°C and the bias voltage requirement is +5Vdc. The rugged and compact package supports SMA female connectors and is designed to meet a series of environmental conditions including Altitude, Vibration, Humidity, and Shock.

Electrical Specifications

TTL Control	Off/Isolation: 0 to 0.8 V On/Low Loss: 2.8 to 5 V				
Description	Minimum	Typical	Maximum	Units	
Frequency Range	DC		6	GHz	
Impedance		50		Ohms	
VSWR		1.35:1	1.5:1		
Insertion Loss		1.5	2	dB	
IL Temperature Coefficient		0.003		dB/degC	
Isolation	25	40		dB	
Switching Time			100	ns	
0.1dB Compression Point		+50		dBm	
Input IP3		50		dBm	
RF Input Power (CW)*			40	Watts	
DC Power Dissipation		1		Watt	

Click the following link (or enter part number in "SEARCH" on website) to obtain additional part information including price, inventory and certifications: Reflective SP4T GaN High Power PIN Diode Switch Operating from DC to 6 GHz Up to 40 Watts (+46 dBm), < 100ns and SMA with Heatsink PE71S1109

Pasternack Enterprises, Inc. • P.O. Box 16759, Irvine, CA 92623 **Phone:** (866) 727-8376 or (949) 261-1920 • **Fax:** (949) 261-7451

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Positive Operating Voltage		5		Vdc
Current @ 5 Vdc		200		mA
Operating Temperature	-45		+85	deg C

Performance by Frequency

	,, ,					
Description	F1	F2	F3	F4	F5	Units
Frequency Range	DC to 3	3 to 6				GHz
VSWR, Max	1.3:1	1.5:1				
VSWR, Typ	1.2:1	1.35:1				
Insertion Loss, Max	1.5	2				dB
Insertion Loss, Typ	1	1.7				dB
Isolation, Min	35	25				dB
Isolation, Typ	42	30				dB

Electrical Specification Notes:

Internal TTL Driver will become damaged if Negative Voltage is applied

*Cold Switching: Before changing any TTL signal(s), the RF input power must be blanked or the switch could become damaged

Absolute Maximum Rating

Parameter	Rating	ESD S
Biasing	+12V±10%	Trai
TTL Control Volta	age 0~0.8V/2.8~5V	

ESD Sensitive Material, Transport material in Approved ESD bags. Handle only in approved ESD Workstation.

Mechanical Specifications

Size Length Width Height Weight Design RF Connector

1.97 in [50.04 mm] 1.97 in [50.04 mm] 0.37 in [9.4 mm] 2.5 lbs [1.13 kg] Reflective, SP4T SMA Female

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Environmental Specifications

Temperature **Operating Range** Storage Range

Humidity Shock Vibration Altitude

-45 to +85 deg C -55 to +125 deg C

100% RH @ 35°C, 95% RH @ 40°C 20G for 11ms Half Sinewave, 3 axis both directions 25g RMS (15° 2KHz) endurance, 1 hr per axis 30,000 ft. (Epoxy Sealed Controlled Environment)

Compliance Certifications (see product page for current document)

Plotted and Other Data

Notes:

Typical Performance Data

dB Insertion Loss 12 10 8 6 4 2 0 -2 -4 -6 -8 0.0 GHz 1.2 1.8 2.4 3.0 4.2 0.6 3.6 4.8 5.4 6.0

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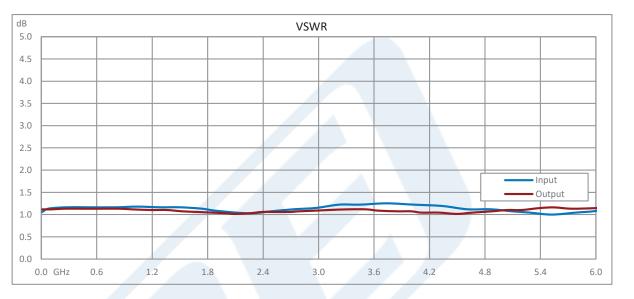
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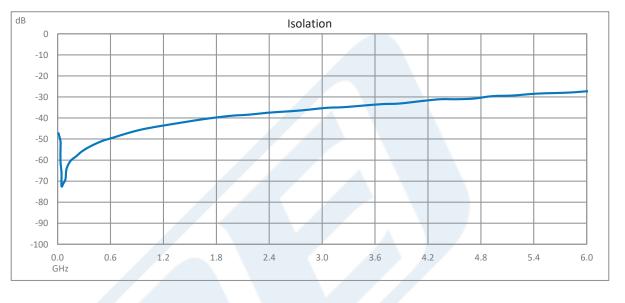
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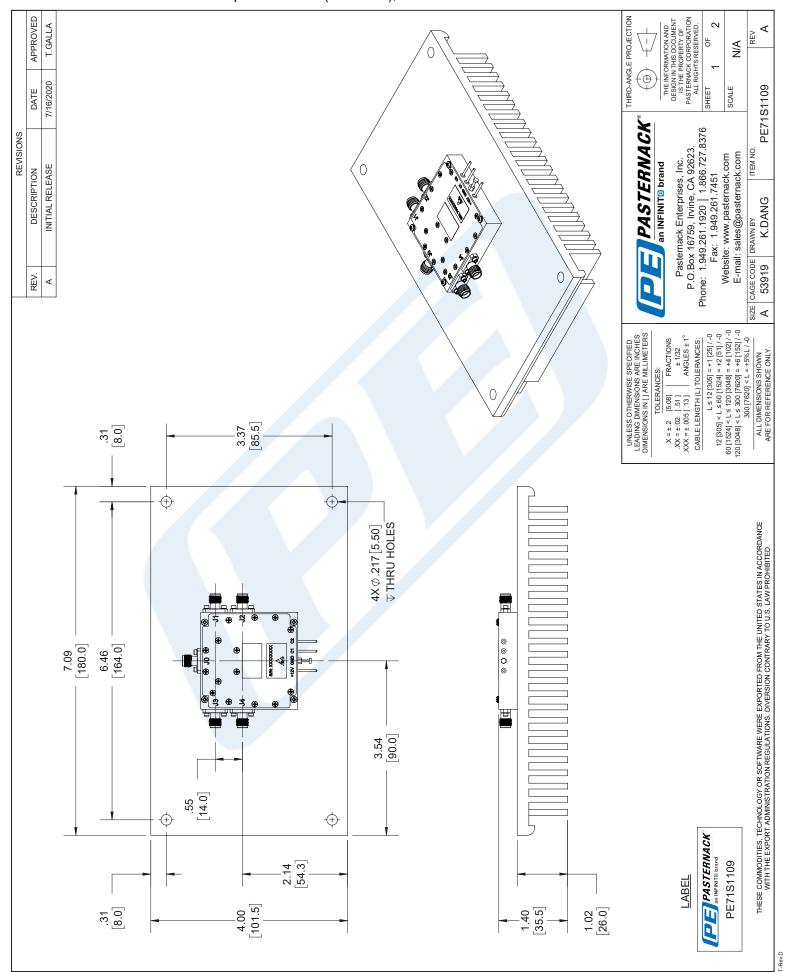
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